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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/890,864	12/21/2001	Wulf Haussler	212603US6	8019	
22850	7590 08/27/2003				
OBLON, SPIVAK, MCCLELLAND, MAIER & NEUSTADT, P.C.			EXAMINER		
1940 DUKE ALEXANDI	STREET RIA, VA 22314		MUTSCHLER, BRIAN L		
			ART UNIT	PAPER NUMBER	
			1753		
			DATE MAILED: 08/27/2003		

Please find below and/or attached an Office communication concerning this application or proceeding.

Advisory Action	09/890,864	HAUSSLER ET AL.	//:				
Advisory Action	Examin r	Art Unit	1)				
	Brian L. Mutschler	1753	V				
The MAILING DATE of this communication app ars on the cover she t with the correspondence address							
THE REPLY FILED 14 August 2003 FAILS TO PLACE THIS APPLICATION IN CONDITION FOR ALLOWANCE. Therefore, further action by the applicant is required to avoid abandonment of this application. A proper reply to a final rejection under 37 CFR 1.113 may only be either: (1) a timely filed amendment which places the application in condition for allowance; (2) a timely filed Notice of Appeal (with appeal fee); or (3) a timely filed Request for Continued Examination (RCE) in compliance with 37 CFR 1.114.							
PERIOD FOR REPLY [check either a) or b)]							
a) The period for reply expires 3 months from the mailing date of b)  The period for reply expires on: (1) the mailing date of this Advevent, however, will the statutory period for reply expire later the ONLY CHECK THIS BOX WHEN THE FIRST REPLY WAS 706.07(f).  Extensions of time may be obtained under 37 CFR 1.136(a). The dath have been filed is the date for purposes of determining the period of extensions of the calculated from: (1) the expiration date of the shortened (b) above, if checked. Any reply received by the Office later than three models.	risory Action, or (2) the date set forth in the an SIX MONTHS from the mailing date on FILED WITHIN TWO MONTHS OF THE teen which the petition under 37 CFR 1.1 sion and the corresponding amount of the statutory period for reply originally set in	f the final rejection. E FINAL REJECTION. S 136(a) and the appropriate ext the final Office action; or	e extension fee ension fee under (2) as set forth in				
earned patent term adjustment. See 37 CFR 1.704(b).	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	· · · · · · · · · · · · · · · · · · ·					
1. A Notice of Appeal was filed on <u>14 August 2003</u> . A 37 CFR 1.192(a), or any extension thereof (37 CF	ppellant's Brief must be filed wi R 1.191(d)), to avoid dismissal	thin the period set f of the appeal.	orth in				
2. The proposed amendment(s) will not be entered because:							
(a) X they raise new issues that would require furth	er consideration and/or search	(see NOTE below);					
(b) ☐ they raise the issue of new matter (see Note below);							
(c) ☐ they are not deemed to place the application in better form for appeal by materially reducing or simplifying the issues for appeal; and/or							
(d) They present additional claims without canceling a corresponding number of finally rejected claims.							
NOTE: See Continuation Sheet.							
3. Applicant's reply has overcome the following reject		,					
4. Newly proposed or amended claim(s) would be allowable if submitted in a separate, timely filed amendment canceling the non-allowable claim(s).							
5.⊠ The a) affidavit, b) exhibit, or c) request for application in condition for allowance because: Se	or reconsideration has been con be Continuation Sheet.	sidered but does NO	OT place the				
6. The affidavit or exhibit will NOT be considered be raised by the Examiner in the final rejection.	cause it is not directed SOLELY	to issues which we	ere newly				
For purposes of Appeal, the proposed amendment(s) a)⊠ will not be entered or b)□ will be entered and an explanation of how the new or amended claims would be rejected is provided below or appended.							
The status of the claim(s) is (or will be) as follows:			•				
Claim(s) allowed:							
Claim(s) objected to:	•						
Claim(s) rejected: 15-44.							
Claim(s) withdrawn from consideration:							
8. The proposed drawing correction filed on is	a) approved or b) disap	proved by the Exan	niner.				
9. Note the attached Information Disclosure Statement	Note the attached Information Disclosure Statement(s)( PTO-1449) Paper No(s)						
0. Other:							

Application No.

Applicant(s)

## Centinuation Sheet (PTOL-303)



Continuation of 2. NOTE: The proposed amendment raises new issues for consideration by presenting the dielectric layer as non-doped zinc oxide layers (see claims 16 and 34). This proposed amendment raises new issues for consideration because dopant-containing zinc oxide layers were not previously excluded.

Continuation of 5. does NOT place the application in condition for allowance because: Applicant's arguments regarding the rejections set forth in the prior Office action are not persuasive because they do not show how the limitations in the instant claims are distinguished over the prior art of record. Applicant asserts that both Weber et al. and Berman et al. use conductive oxide layers or oxide layers that are easily doped to improve their conductivity. While this fact is true, in the broadest interpretation of Applicant's claims, doped oxide layers are included. On page 2 of the instant disclosure, Applicant discloses, "If zinc oxide (ZnO) or another transparent oxide is used as material for the window electrode, this material, which is dielectric in itself, must be deposited as a doped semiconductor." Furthermore, on page 5 of the instant disclosure, Applicant states, "[I]t is also of little importance of whether or not [the highly refractive layer] is electrically conductive." Using the broadest interpretation, it appears that zinc oxide is a dielectric material, and the dopants, while making the zinc oxide conductive, could be considered "additives" to the dielectric material that make it conductive. It is also noted that Applicant discloses, "It has also been observed that a relatively thin layer...of dielectric ZnO between the absorber layer and the window layer of ZnO made conductive by doping increases the efficiency of the solar cell" (see page 3, second full paragraph). An example of this is taught by Chen et al. in U.S. Pat. No. 5,078,804, which includes both high conductivity ZnO layers (50a) and high resistivity ZnO layers (50b).

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